

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	IS&R	L2	1606	(257/382,401).CCLS.	USPAT	2005/12/10 17:56
2	IS&R	L3	680	(257/382,401).CCLS.	US- PGPUB; USOCR; EPO; JPO; DERWE NT; IBM_TD B	2005/12/10 17:58
3	IS&R	L4	1016	(438/284,286,300).CCLS.	USPAT	2005/12/10 17:57
4	IS&R	L5	268	(438/284,286,300).CCLS.	US- PGPUB; USOCR; EPO; JPO; DERWE NT; IBM_TD B	2005/12/10 18:00
5	IS&R	L6	3475	(257/688-692,698,699).CCLS.	USPAT	2005/12/10 17:59
6	IBRS	L7	200	6 and ((source with drain) (source/drain) s/d)	USPAT	2005/12/10 17:59
7	IBRS	L8	21	chip adj surface adj electrode	USPAT	2005/12/10 18:00
8	IBRS	L10	43	chip adj surface adj electrode	US- PGPUB; USOCR; EPO; JPO; DERWE NT; IBM_TD B	2005/12/10 18:01

	Type	L #	Hits	Search Text	DBs	Time Stamp
9	BRS	L12	2	((top upper uppermost) and (electrode conductive conductor metal) and (control adj electrode) and (ground potential) and (organic polymer polyimide)).clm.	US- PGPUB	2005/12/10 18:15